

FS6S0965RCB

Fairchild Power Switch(FPS)

Features

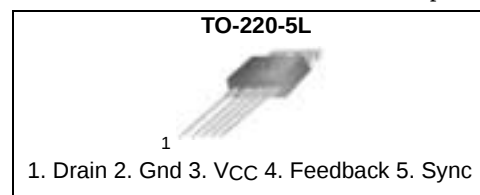
- Wide Operating Frequency Range up to 150kHz
- Lowest Cost SMPS Solution
- Lowest External Components
- Low Start up Current (Max:170uA)
- Low Operating Current (Max:15mA)
- Internal High Voltage SenseFET
- Built-in Auto Restart Circuit
- Over Voltage Protection (Auto Restart Mode)
- Over Load Protection (Auto Restart Mode)
- Over Current Protection (Auto Restart Mode)
- Internal Thermal Protection(Auto Restart Mode)
- Pulse By Pulse Over Current Limiting
- Internal Burst Mode Controller for Stand-by Mode
- Under Voltage Lockout With Hysteresis
- External Sync. Terminal

Application

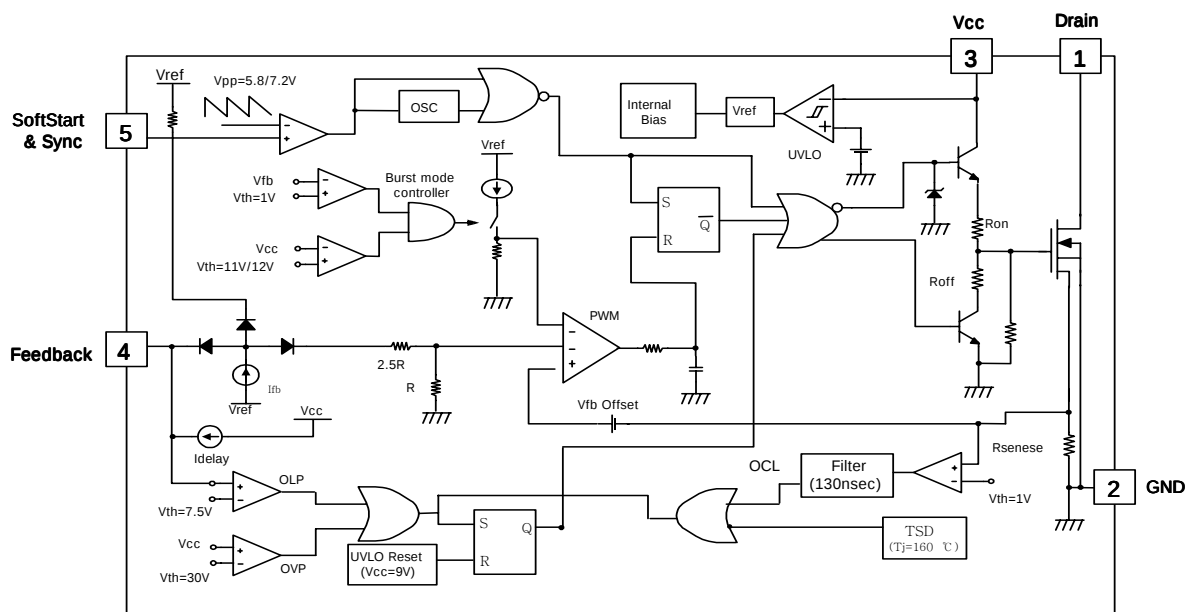
- Monitor SMPS

Description

The Fairchild Power Switch(FPS) product family are specially designed for an off line SMPS with minimal external components. The Fairchild Power Switch(FPS) consists of a high voltage power SenseFET and a current mode PWM IC. Included PWM controller features the integrated fixed oscillator, the under voltage lockout, the optimized gate turn on/turn off driver, the thermal shut down protection, the over voltage protection, and the temperature compensated precision current sources for the loop compensation and the fault protection circuitry. Compared to a discrete MOSFET and a controller or a RCC switching converter solution, a Fairchild Power Switch(FPS) can reduce the total component count, design size, and weight and at the same time increase efficiency, productivity, and system reliability. It has a basic platform well suited for the cost effective monitor power supply.



Internal Block Diagram



Rev.1.0.1

Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Gate Voltage (R _{GS} =1MΩ)	V _{DGR}	650	V
Gate-Source (GND) Voltage	V _{GS}	±30	V
Drain Current Pulsed ⁽²⁾	I _{DM}	32.4	A _{DC}
Single Pulsed Avalanche Energy ⁽³⁾	E _{AS}	515	mJ
Single Pulsed Avalanche Current ⁽⁴⁾	I _{AS}	25	A
Continuous Drain Current (T _c = 25°C)	I _D	8.1	A _{DC}
Continuous Drain Current (T _C =100°C)	I _D	5.1	A _{DC}
Supply Voltage	V _{CC}	35	V
Input Voltage Range	V _{FB}	-0.3 to V _{CC}	V
	V _{S_S}	-0.3 to 10	V
Total Power Dissipation	P _D (Watt H/S)	155	W
	Derating	1.243	W/°C
Operating Junction Temperature	T _J	+150	°C
Operating Ambient Temperature	T _A	-25 to +85	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

Notes:

1. T_J=25°C to 150°C
2. Repetitive rating: Pulse width limited by maximum junction temperature
3. L=14.5mH, starting T_J=25°C
4. L=13uH, starting T_J=25°C

Electrical Characteristics (SenseFET part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	650	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =650V, V _{GS} =0V	-	-	200	μA
		V _{DS} =520V V _{GS} =0V, T _C =125°C	-	-	300	μA
Static Drain-Source On Resistance ⁽¹⁾	R _{DS(ON)}	V _{GS} =10V, I _D =1.8A	-	1.0	1.2	Ω
Forward Transconductance ⁽²⁾	g _{fs}	V _{DS} =50V, I _D =1.8A	-	-	-	S
Input Capacitance	C _{iss}	V _{GS} =0V, V _{DS} =25V, f = 1MHz	-	1300	-	pF
Output Capacitance	C _{oss}		-	135	-	
Reverse Transfer Capacitance	C _{rss}		-	25	-	
Turn On Delay Time	t _{d(on)}	V _{DD} =325V, I _D =6.5A (MOSFET switching time is essentially independent of operating temperature)	-	25	-	nS
Rise Time	t _r		-	75	-	
Turn Off Delay Time	t _{d(off)}		-	130	-	
Fall Time	t _f		-	70	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Q _g	V _{GS} =10V, I _D =6.5A, V _{DS} =520V (MOSFET switching time is essentially independent of operating temperature)	-	45	60	nC
Gate-Source Charge	Q _{gs}		-	8	-	
Gate-Drain (Miller) Charge	Q _{gd}		-	21	-	

Notes:

1. Pulse test : Pulse width ≤ 300μS, duty 2%

2. $S = \frac{1}{R}$

Electrical Characteristics (Continued)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
UVLO SECTION						
Start Threshold Voltage	VSTART	V _{FB} =GND	14	15	16	V
Stop Threshold Voltage	VSTOP	V _{FB} =GND	8	9	10	V
OSCILLATOR SECTION						
Initial Frequency	FOSC	-	22	25	28	kHz
Voltage Stability	FSTABLE	12V ≤ V _{CC} ≤ 23V	0	1	3	%
Temperature Stability (4)	ΔFOSC	-25°C ≤ Ta ≤ 85°C	0	±5	±10	%
Maximum Duty Cycle	DMAX	-	92	95	98	%
Minimum Duty Cycle	DMIN	-	-	-	0	%
FEEDBACK SECTION						
Feedback Source Current	I _{FB}	V _{FB} =GND	0.7	0.9	1.1	mA
Shutdown Feedback Voltage	V _{SD}	V _{fb} ≥ 6.9V	6.9	7.5	8.1	V
Shutdown Delay Current	I _{delay}	V _{FB} =5V	1.6	2.0	2.4	μA
SYNC & SOFTSTART SECTION						
Softstart Vortage	V _{SS}	V _{fb} =2	4.7	5.0	5.3	V
Softstart Current	I _{SS}	V _{ss} =V	0.8	1.0	1.2	mA
Sync High Threshold Voltage	V _{SYNCH}	V _{CC} =16V, V _{fb} =5V	-	7.2	-	V
Sync Low Threshold Voltage	V _{SYNCL}	V _{CC} =16V, V _{fb} =5V	-	5.8	-	V
BURST MODE SECTION						
Burst Mode Low Threshold Voltage	V _{BURL}	V _{fb} =0V	10.4	11.0	11.6	V
Burst Mode High Threshold Voltage	V _{BURH}	V _{fb} =0V	11.4	12.0	12.6	V
Burst Mode Enable Feedback Voltage(4)	V _{BEN}	V _{CC} =10.5V	0.7	1.0	1.3	V
Burst Mode Peak Current Limit(3)	I _{BU_PK}	V _{CC} =10.5V	0.45	0.6	0.75	V
Burst Mode Frequency	F _{BUR}	V _{CC} =10.5V, V _{fb} =0V	40	50	60	kHz
CURRENT LIMIT(SELF-PROTECTION)SECTION						
Peak Current Limit(3)	I _{OVER}	-	5.28	6.0	6.72	A
PROTECTION SECTION						
Over Voltage Protection	V _{OV} P	V _{CC} ≥ 27V	27	30	33	V
Over Current Latch Voltage (2)	V _{OCL}	-	0.9	1.0	1.1	V
Thermal Shutdown Temperature(4)	T _{SD}	-	140	160	-	°C
TOTAL DEVICE SECTION						
Start Up Current	I _{START}	V _{fb} =GND, V _{CC} =14V	-	0.1	0.17	mA
Operating Supply Current (1)	I _{OP}	V _{fb} =GND, V _{CC} =16V	-	10	15	mA
	I _{OP(MIN)}	V _{fb} =GND, V _{CC} =10V				
	I _{OP(MAX)}	V _{fb} =GND, V _{CC} =28V				

Note:

1. These parameters are the current flowing in the control IC.
2. These parameters, although guaranteed, are tested in the EDS(wafer test) process.
3. These parameters indicate the inductor current.
4. These parameters, although guranteed at the design, are not tested in the mass production

Typical Performance Characteristics

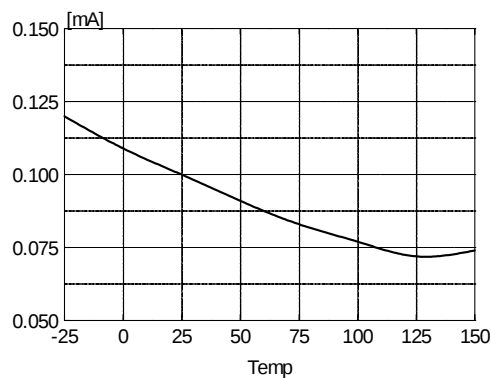


Figure 1. Start Up Current vs. Temp.

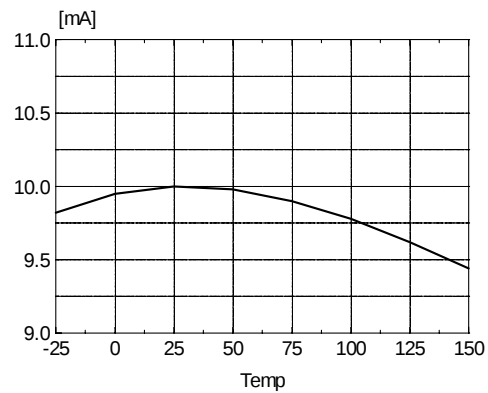


Figure 2. Operating Current vs. Temp.

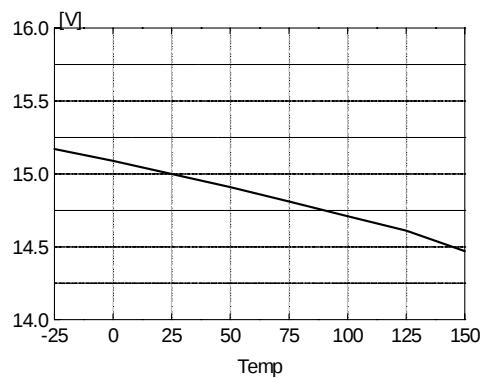


Figure 3. Start Threshold Voltage vs. Temp.

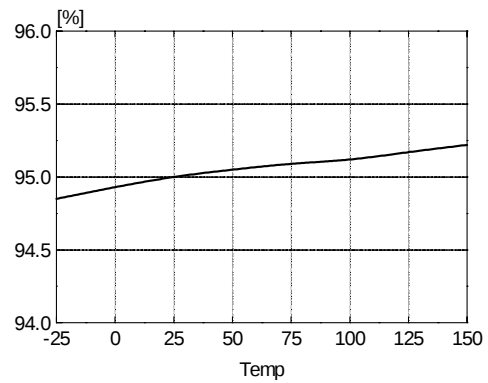


Figure 4. Stop Threshold Voltage vs. Temp.

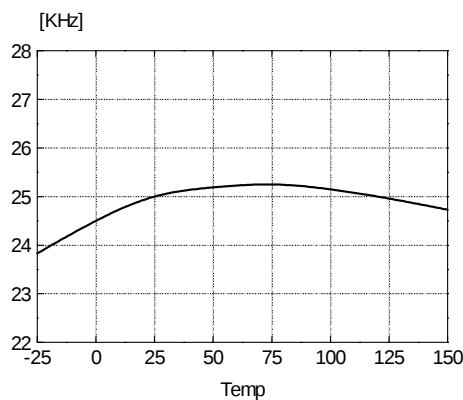


Figure 5. Initial Frequency vs. Temp.

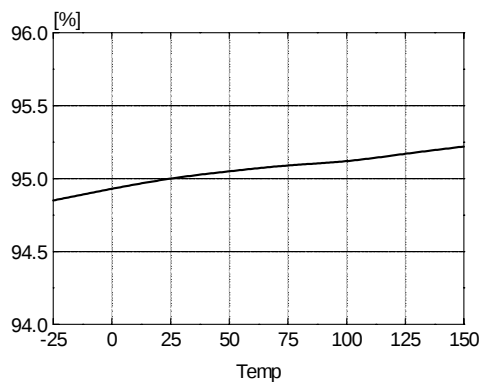


Figure 6. Maximum Duty vs. Temp.

Typical Performance Characteristics (Continued)

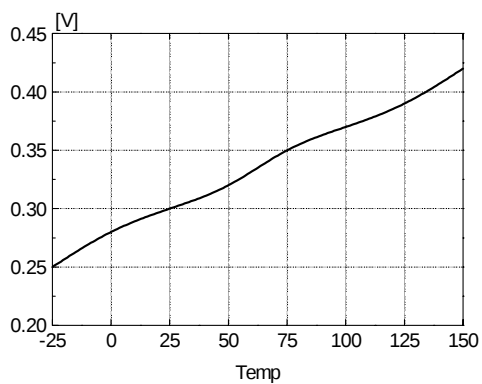


Figure 7. Feedback Offset Voltage vs. Temp.

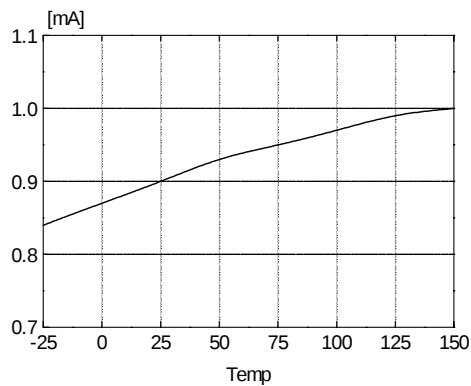


Figure 8. Feedback Source Current vs. Temp.

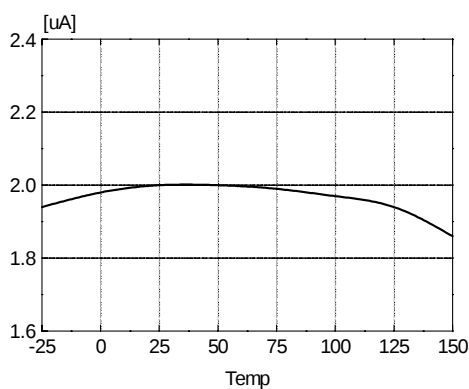


Figure 9. Shutdown Delay Current vs. Temp.

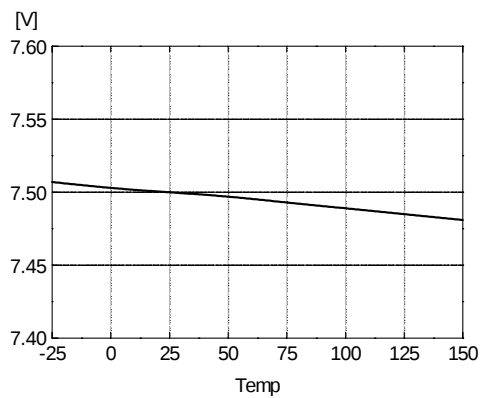


Figure 10. Shutdown Feedback Voltage vs. Temp.

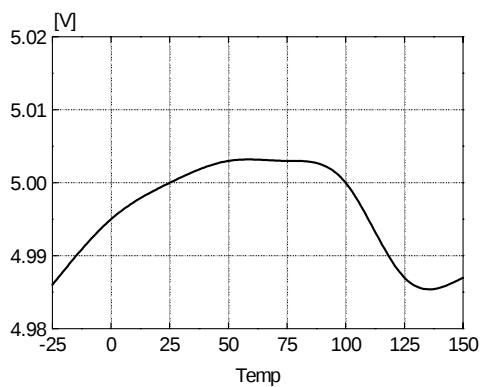


Figure 11. Softstart Voltage vs. Temp.

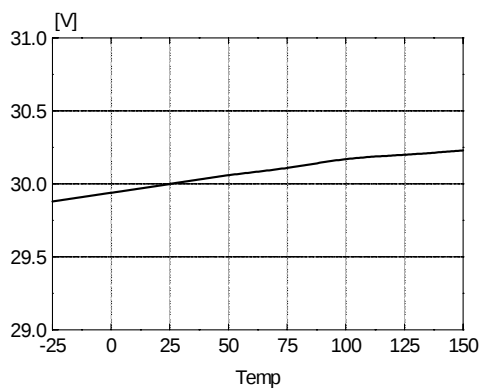


Figure 12. Over Voltage Protection vs. Temp.

Typical Performance Characteristics (Continued)

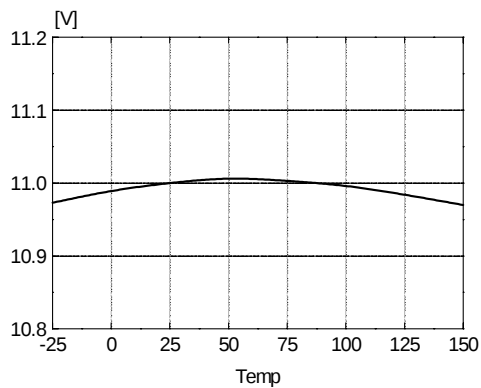


Figure 13. Burst Mode Low Voltage vs. Temp.

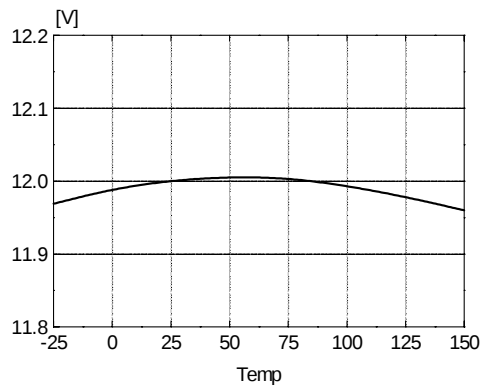


Figure 14. Burst Mode High Voltage vs. Temp.

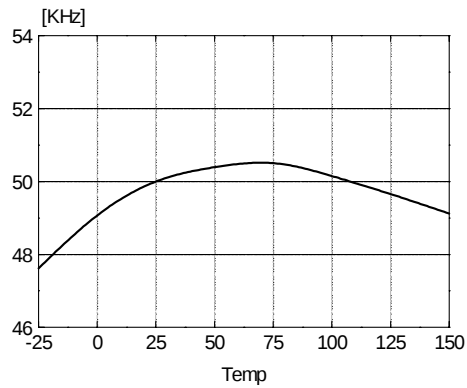


Figure 15. Burst Mode Frequency vs. Temp.

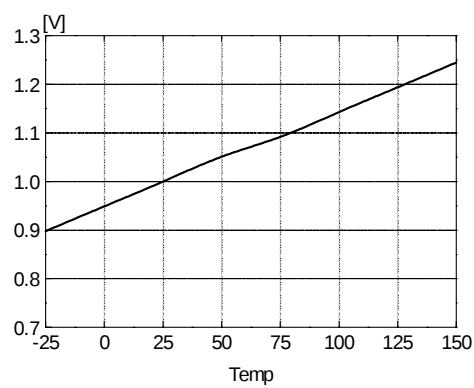


Figure 16. Burst Mode Enable Voltage vs. Temp.

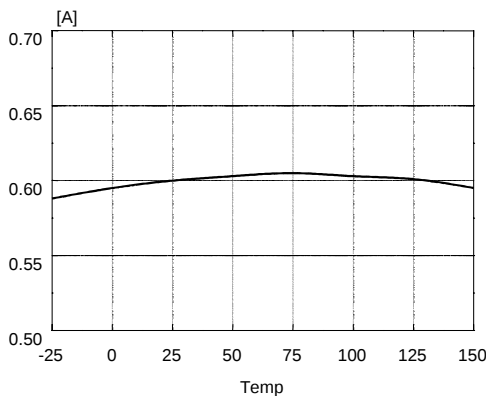


Figure 17. Burst Mode Peak Current vs. Temp.

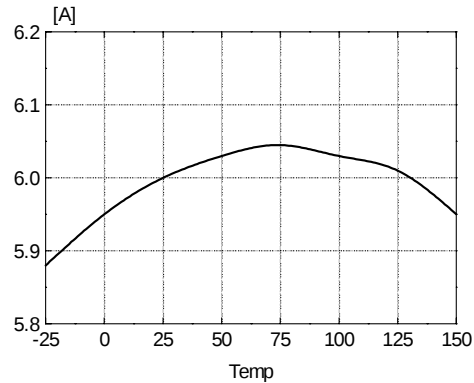


Figure 18. Over Current Limit vs. Temp.

TO-220-5L



Ordering Information

Product Number	Package	Marking Code	BVdss	Rds(on)
FS6S0965RCBTU	TO-220-5L	6S0965RC B	650V	1.0
FS6S0965RCBYDTU	TO-220-5L(Forming)			

TU : Non Forming Type

YDTU : Forming Type

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